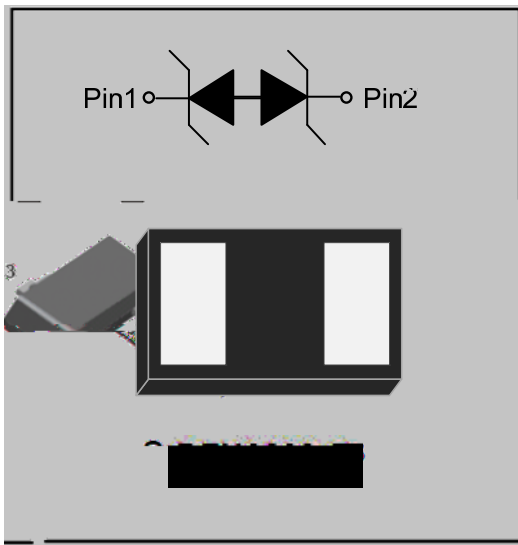


1-Line, Bi-directional, Transient Voltage Suppressor



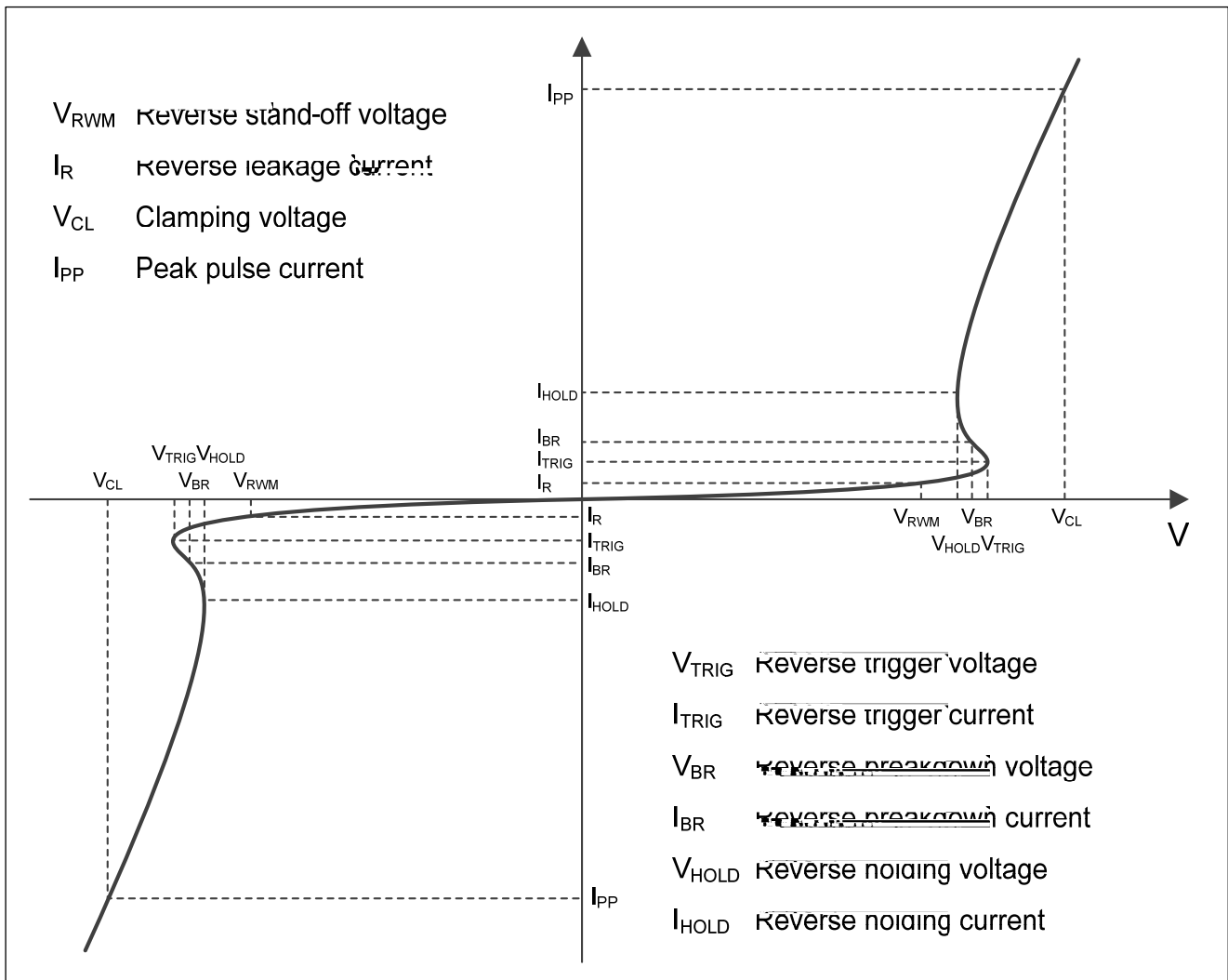
Features

- Stand-off voltage: $\pm 7\text{V}$ Max
- Transient protection for each line according to IEC61000-4-2(ESD): $\pm 30\text{kV}$ (contact)
IEC61000-4-4 (EFT): 40A (5/50ns)
IEC61000-4-5(surge): 6A (8/20 μs)
- Ultra-low capacitance: $C_j = 10\text{pF}$ typ
- Low leakage current
- Low clamping voltage: $V_{CL} = 11.0\text{V}$ typ. @ $I_{PP} = 16\text{A}$ (TLP)
- Solid-state silicon technology

Mechanical Data

- **Package:** DFN0603-2L
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** No marking on bi-directional types
- **Marking:** A7

■Definitions of electrical characteristics





ESD7V0LZB

■Maximum Ratings

PARAMETER	SYMBOL	Rating	UNIT
Peak pulse power ($t_p = 8/20\mu s$)	P_{pk}	84	W
Peak pulse current ($t_p = 8/20\mu s$)	I_{PP}	6	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	KV
ESD according to IEC61000-4-2 contact discharge		± 30	KV
Junction temperature	T_J	125	$^{\circ}C$
Operating temperature	T_{OP}	-40~85	$^{\circ}C$
Storage temperature	T_{STG}	-55~150	$^{\circ}C$

■Electrical Characteristics $T_a=25$ Unless otherwise specified

PARAMETER	Symbol	UNIT	Conditions	Min	Typ	Max
Reverse maximum working voltage	V_{RWM}	V				± 7
Reverse leakage current	I_R	nA	$V_{RWM} = 7V$			100
Reverse breakdown voltage	V_{BR}	V	$I_{BR} = 1mA$	7.2		10.5
Reverse holding voltage	V_{HOLD}	V	$I_{HOLD} = 50mA$	7.2		10.5
Clamping voltage ¹⁾	V_{CL}	V	$I_{PP} = 16A, t_p = 100ns$		12.0	
Dynamic resistance ¹⁾	R_{DYN}	Ω			0.28	
Clamping voltage ²⁾	V_{CL}	V	$V_{ESD} = 8kV$		12.0	
Clamping voltage ³⁾	V_{CL}	V	$I_{PP} = 1A, t_p = 8/20\mu s$		9	11
		V	$I_{PP} = 6A, t_p = 8/20\mu s$		12	14
Junction capacitance	C_J	pF	$V_R = 0V, f = 1MHz$		10	13
		pF	$V_R = 2.5V, f = 1MHz$		8	11

(1). TLP parameter: $Z_0 = 50\Omega$, $t_p = 100ns$, $t_r = 2ns$, averaging window from 60ns to 80ns. R_{DYN} is calculated from 4A to 16A.

(2). Contact discharge mode, according to IEC61000-4-2.

(3). Non-repetitive current pulse, according to IEC61000-4-5.

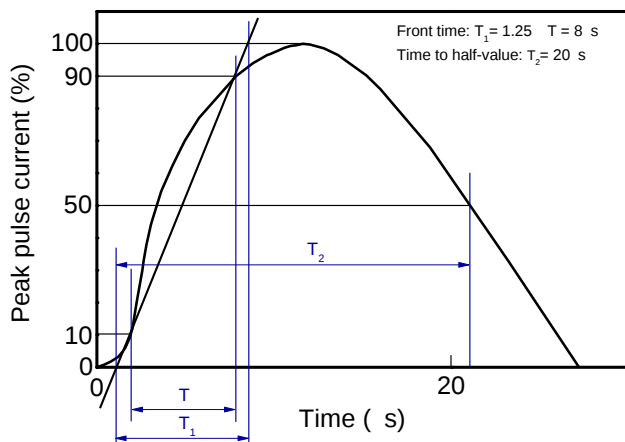
■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
ESD7V0LZB	Approximate 0.18	10000	100000	400000	Tape& reel

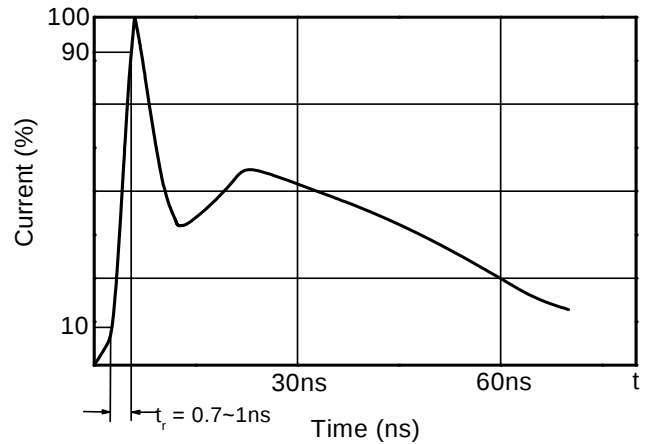


■ Characteristics (Typical)

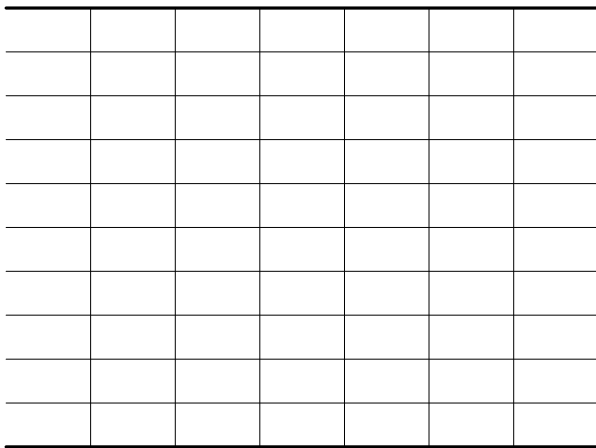
8/20 μ s waveform per IEC61000-4-5



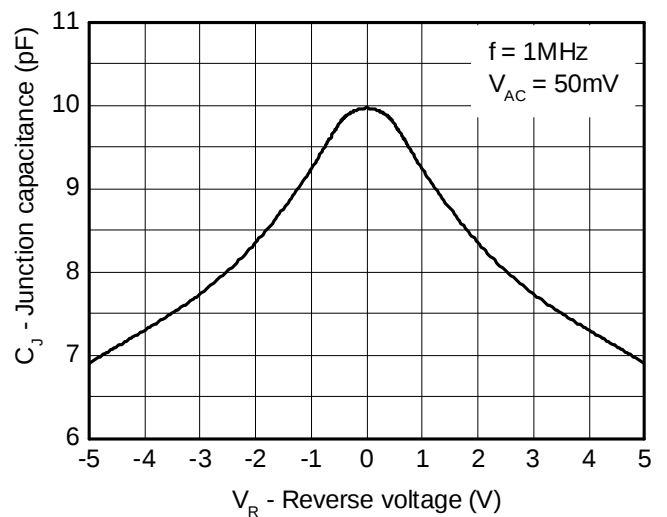
Contact discharge current waveform per IEC61000-4-2



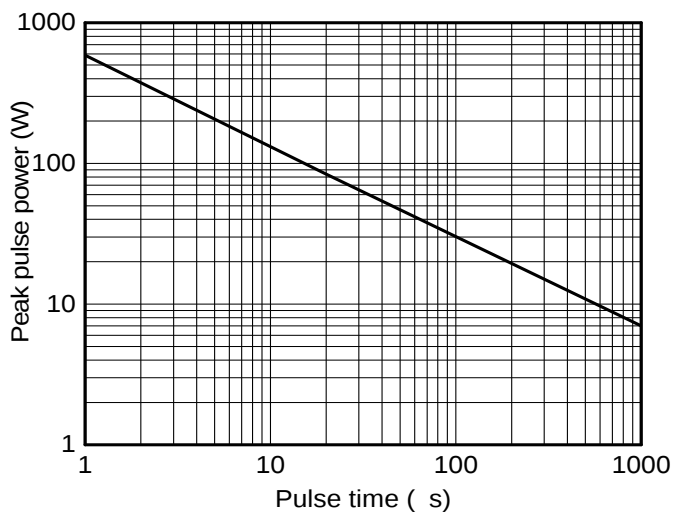
Clamping voltage vs. Peak pulse current



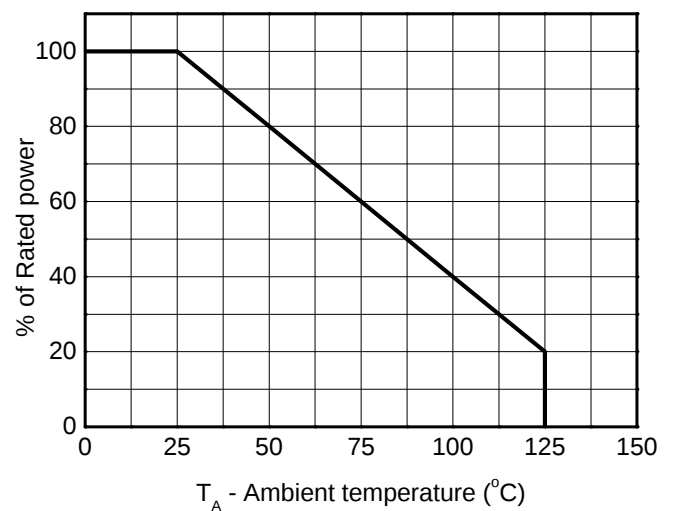
Capacitance vs. Reverse voltage



Non-repetitive peak pulse power vs. Pulse time

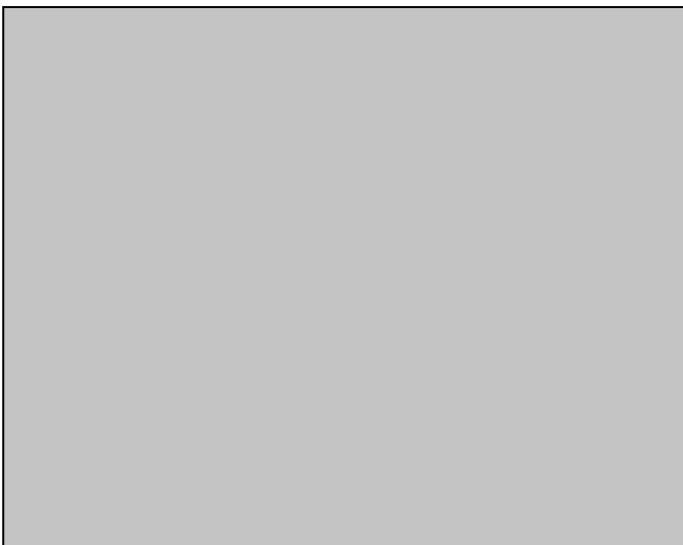


Power derating vs. Ambient temperature





ESD clamping clamping





■ Recommend land pattern (Unit:mm)



Notes:

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met



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